PCTEST ENGINEERING LABORATORY, INC.

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HEARING AID COMPATIBILITY CERTIFICATE

Applicant Name:

Samsung Electronics, Co. Ltd. 18600 Broadwick St. Rancho Dominguez, CA 90220 USA **United States**

Date of Testing: October 3 - 5, 2006 Test Site/Location:

PCTEST Lab, Columbia, MD, USA **Test Report Serial No.:**

0609280859

FCC ID: A3LSCHU520

APPLICANT: SAMSUNG ELECTRONICS, CO. LTD.

Application Type: Class II Permissive Change § 20.19(b), §6.3(v), §7.3(v) FCC Rule Part(s): **HAC Standard:** ANSI C63.19-2006 v3.12;

FCC Classification: Licensed Transmitter Held to Ear (PCE)

Dual-Band CDMA Phone with Bluetooth and EVDO **EUT Type:**

Model(s): SCH-U520

Tx Frequency: 824.70 - 848.31 MHz (Cellular CDMA) 1851.25 - 1908.75 MHz (PCS CDMA)

Test Device Serial No.: Pre-Production Sample [S/N: 1C140426]

See Attachment Class II Permissive Change(s):

C63.19 HAC Rated Category: **M4 (RF EMISSIONS CATEGORY)**

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2006 and had been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

PCTEST certifies that no party to this application has been denied the FCC benefits pursuant to Section 5301 of the Anti-Drug Abuse Act of 1988, 21 U.S.C. 862.

Randy Ortanez President



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1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658¹ to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- RF Magnetic-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1 Hearing Aid in-vitu

¹ FCC Rule & Order, WT Docket 01-309 RM-8658

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TEST SITE LOCATION 2.

2.1 INTRODUCTION

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the FCC Laboratory, the Baltimore-Washington International (BWI) airport, the city of Baltimore and Washington, DC (See Figure 2).

These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in New Concept Business Park, Guilford Industrial Park, Columbia, Maryland. The site address is 6660-B Dobbin Road, Columbia, MD 21045. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 11'15" N latitude and 76° 49' 38" W longitude. The facility is 1.5 miles North of the FCC laboratory, and the ambient signal and ambient signal strength are approximately equal to those of the FCC laboratory. There are no FM or TV

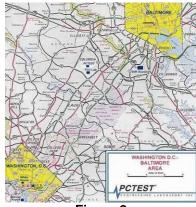


Figure 2 Map of the Greater Baltimore and Metropolitan Washington, D.C. area

transmitters within 15 miles of the site. The detailed description of the measurement facility was found to be in compliance with the requirements of § 2.948 according to ANSI C63.4 on January 27, 2006 and Industry Canada.

2.2 Test Facility / Accreditations:

Measurements were performed at an independent accredited PCTEST Engineering Lab located in Columbia, MD 21045, U.S.A.



- PCTEST Lab is accredited to ISO 17025-2005 by the American Association for Laboratory Accreditation (A2LA) in Specific Absorption Rate (SAR) testing. Hearing-Aid Compatibility (HAC), CTIA Test Plans, and wireless testing for FCC and Industry Canada Rules.
- PCTEST Lab is accredited to ISO 17025 by U.S. National Institute of Standards and Technology (NIST) under the National Voluntary Laboratory Accreditation Program (NVLAP Lab code: 100431-0) in EMC, FCC and Telecommunications.
- PCTEST facility is an FCC registered (PCTEST Reg. No. 90864) test facility with the site description report on file and has met all the requirements specified in Section 2.948 of the FCC Rules and Industry Canada (IC-2451).
- PCTEST Lab is a recognized U.S. Conformity Assessment Body (CAB) in EMC and R&TTE (n.b. 0982) under the U.S.-EU Mutual Recognition Agreement (MRA).
- PCTEST TCB is a Telecommunication Certification Body (TCB) accredited to ISO/IEC Guide 65 by the American National Standards Institute (ANSI) in all scopes of FCC Rules and all Industry Canada Standards (RSS).
- PCTEST facility is an IC registered (IC-2451) test laboratory with the site description on file at Industry Canada.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for AMPS and CDMA, and EvDO mobile phones.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for Over-the-Air (OTA) Antenna Performance testing for AMPS, CDMA, GSM, GPRS, EGPRS, UMTS (W-CDMA), CDMA 1xEVDO Data, CDMA 1xRTT Data.

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EUT DESCRIPTION 3.



FCC ID: A3LSCHU520

Manufacturer: Samsung Electronics, Co. Ltd.

18600 Broadwick St.

Rancho Dominguez, CA 90220 USA

United States

Trade Name: **SAMSUNG** Model(s): **SCH-U520** Serial Number: 1C140426

Tx Frequencies: 824.70 - 848.31 MHz (Cellular CDMA)

1851.25 - 1908.75 MHz (PCS CDMA)

Antenna Configurations: Internal Antenna

Maximum Conducted Power (EMC/SAR): Maximum Conducted

25 dBm (CDMA), 25 dBm (CDMA PCS)

25 dBm (CDMA), 25 dBm (CDMA PCS) Power (HAC):

HAC Test Configurations: CDMA, 1013, 384, 777, BT Off PCS, 25, 600, 1175, BT Off

FCC Classification: Licensed Transmitter Held to Ear (PCE)

EUT Type: Dual-Band CDMA Phone with Bluetooth and EVDO

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4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters					
Near field Category	E-field emissions CW dB(V/m)	H-field emissions CW dB(A/m)				
f < 960 MHz						
M1	56 to 61 + 0.5 x AWF	5.6 to 10.6 +0.5 x AWF				
M2	51 to 56 + 0.5 x AWF	0.6 to 5.6 +0.5 x AWF				
M3	46 to 51 + 0.5 x AWF	-4.4 to 0.6 +0.5 x AWF				
M4	< 46 + 0.5 x AWF	< -4.4 + 0.5 x AWF				
	f > 960 MHz					
M1	46 to 51 + 0.5 x AWF	-4.4 to 0.6 +0.5 x AWF				
M2	41 to 46 + 0.5 x AWF	−9.4 to −4.4 +0.5 x AWF				
M3	36 to 41 + 0.5 x AWF	-14.4 to -9.4 +0.5 x AWF				
M4	< 36 + 0.5 x AWF	< -14.4 + 0.5 x AWF				
Table 4-1 Hearing aid and WD near-field categories as defined in ANSI C63.19-2006 v3.12 [2]						

II. ARTICULATION WEIGHTING FACTOR (AWF)

Standard	Technology	Articulation Weighing Factor (AWF)				
T1/T1P1/3GPP	UMTS (WCDMA)	0				
IS-95	CDMA	0				
iDEN [™]	TDMA (22 and 11 Hz)	0				
J-STD-007 GSM (217 Hz) -5						
Table 4-2 Articulation Weighting Factors						

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5. SYSTEM SPECIFICATIONS

ER3DV6 E-Field Probe Description

One dipole parallel, two dipoles normal to probe axis Construction:

Built-in shielding against static charges

Calibration: In air from 100 MHz to 3.0 GHz

(absolute accuracy ±6.0%, k=2)

Frequency: 100 MHz to > 6 GHz;

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

± 0.2 dB in air (rotation around probe axis) Directivity

± 0.4 dB in air (rotation normal to probe axis)

2 V/m to > 1000 V/m Dynamic Range

(M3 or better device readings fall well below diode

compression point)

Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm



Figure 3 E-field Free-space Probe

H3DV6 H-Field Probe Description

Construction: Three concentric loop sensors with 3.8 mm loop diameters

Resistively loaded detector diodes for linear response

Built-in shielding against static charges

Frequency: 200 MHz to 3 GHz (absolute accuracy ± 6.0%, k=2);

Output linearized

± 0.25 dB (spherical isotropy error) Directivity:

10 mA/m to 2 A/m at 1 GHz Dynamic Range:

(M3 or better device readings fall well below diode

compression point)

Overall length: 330 mm (Tip: 40 mm) Dimensions:

Tip diameter: 6 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 3 mm

E-Field < 10% at 3 GHz (for plane wave)

Interference:



Figure 4 H-Field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

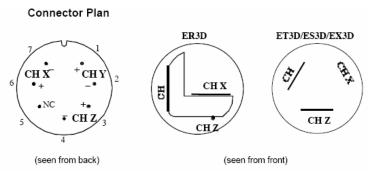
Magnetic field sensors are measuring the integral of the H-field across their sensor area surrounded by the loop. They are calibrated in a precise, homogeneous field. When measuring a gradient field, the result will be very close to the field in the center of the loop which is equivalent to the value of a homogeneous field equivalent to the center value. But it will be different from the field at the border of the loop.

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Consequently, two sensors with different loop diameters - both calibrated ideally - would give different results when measuring from the edge of the probe sensor elements. The behavior for electrically small E-field sensors is equivalent.

The magnetic field loops of the H3D probes are concentric, with the center 3mm from the tip for H3DV6. Their radius is 1.9mm.

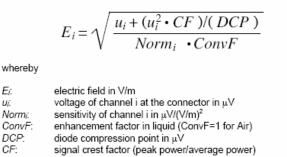
The electric field probes have a more irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.



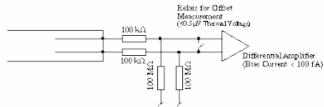
The antistatic shielding inside the probe is connected to the probe connector case.

Instrumentation Chain

Equation 1 Conversion of Connector Voltage u, to E-Field E,



Conditions of Calibration



Please note:

- a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP
- larger bias currents will cause higher offset

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Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

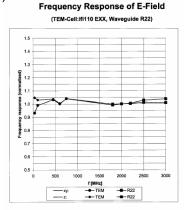


Figure 5 E-Field Probe Frequency Response

H-field sensors have a frequency dependent sensitivity which is evaluated for a series of frequencies also visible in the probe calibration certificate. The calibration factors result from a fitting algorithm. The proper conversion is calculated by the DASY4 software depending on the frequency setting in the procedure. See below for H-field frequency response:

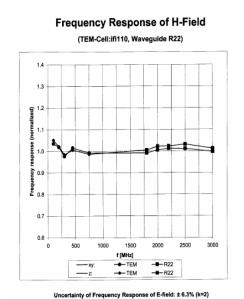


Figure 6 H-Field Probe Frequency Response

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Conversion to Peak

Peak is defined as Peak Envelope Power. All raw measurements from the HAC measurement system are RMS values. The DASY4 system incorporates the crest factor of the signal in the computation of the RMS values (See Equation 1). Although the software also has capability to estimate the peak field by applying a square root of crest factor value to the readings, the probe modulation factor was applied manually instead per C63.19 in the measurement tables in this report. The equation to convert the raw measurements in the data tables are:

Peak Field = 20·log (Raw · PMF)

Where:

Peak Field = Peak field (in dBV/m or dBA/m)

Raw = Raw field measurement from the measurement system (in V/m or A/m).

PMF = Probe Modulation Factor (in linear units).

SPEAG Robotic System

E-field and H-field measurements are performed using the DASY4 automated dosimetric assessment system. The DASY4 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Pentium 4 computer, nearfield probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 7 SPEAG Robotic System

System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the Gateway Pentium 4 2.53 GHz computer with Windows XP system and RF Measurement Software DASY4 v4.5 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

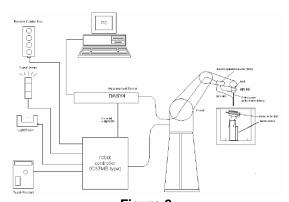


Figure 8 SPEAG Robotic System Diagram

DASY4 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$\begin{aligned} V_i &= U_i + U_i^2 \cdot \frac{cf}{dcp_i} \\ \text{with} \quad V_i &= \text{compensated signal of channel i} & (i = x, y, z) \\ U_i &= \text{input signal of channel i} & (i = x, y, z) \\ cf &= \text{crest factor of exciting field} & (\text{DASY parameter}) \\ dcp_i &= \text{diode compression point} & (\text{DASY parameter}) \end{aligned}$$

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From the compensated input signals the primary field data for each channel can be evaluated:

E – field
probes :
$$E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

$$H$$
 – field
probes : $H_i = \sqrt{V_i} \cdot \frac{a_{i0} + a_{i1}f + a_{i2}f^2}{f}$

with
$$V_i$$
 = compensated signal of channel i (i = x, y, z)

= sensor sensitivity of channel i $\mu V/(V/m)^2$ for E-field Probes

= sensitivity enhancement in solution ConvF

= sensor sensitivity factors for H-field probes a_{ij}

f = carrier frequency [GHz]

 E_i = electric field strength of channel i in V/m H_i = magnetic field strength of channel i in A/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500 ms.

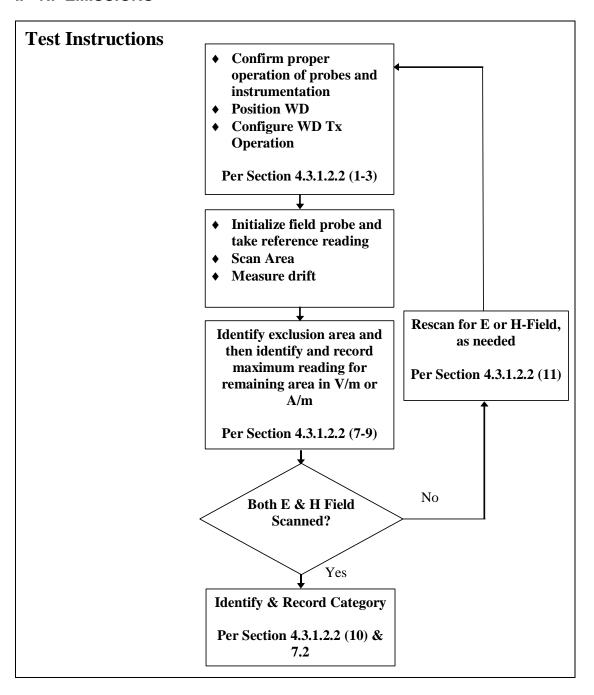
The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500 ms and a probe response time of <5 ms. In the current implementation, DASY4 waits longer than 100 ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

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6. **TEST PROCEDURE**

I. RF EMISSIONS



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Test Setup

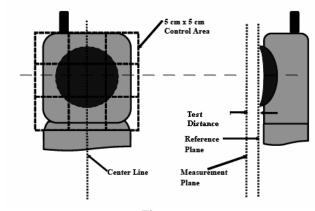


Figure 9 E/H-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

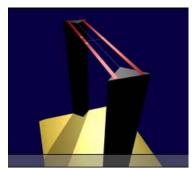


Figure 10 HAC Phantom

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm increments in the 5 x 5 cm region were performed at a distance 1 cm from the probe elements to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location.
- 9. Steps 1-8 were done for both the E and H-Field measurements.

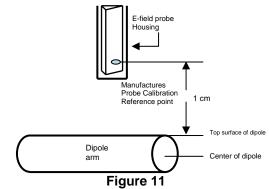
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7. SYSTEM CHECK

System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 1 cm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device (e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (i.e. - 20dBm) RMS after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned with both E-field and H-field probes and the maximum values for each were recorded.

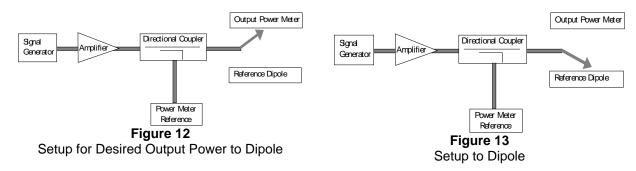
Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (

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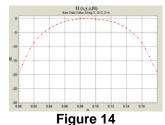
see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

RF power was recorded using both an average and a peak power reading meter.

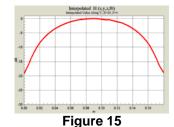


Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 13.

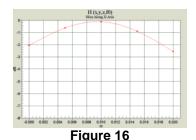
The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



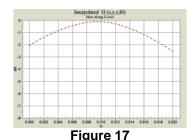
2-D Raw Data from scan along dipole axis



2-D Interpolated points from scan along dipole axis



2-D Raw Data from scan along transverse axis



2-D Interpolated points from scan along transverse axis

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III. System Check Results

Validation Results

Frequency (MHz)	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
835	20.0	178.9	185.1	-3.4%
1880	20.0	135.0	145.8	-7.4%
Erogueney	Input	H-field	Target	
Frequency (MHz)	Power (dBm)	Result (A/m)	Field (A/m)	% Deviation
	Power		Field	, ,

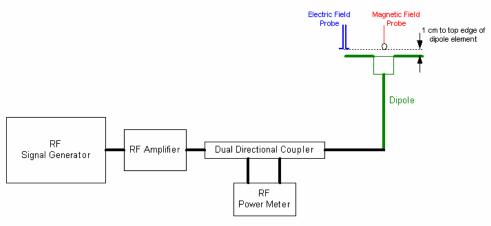


Figure 18 System Check Setup

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MODULATION FACTOR 8.

A calibration was made of the modulation response of the probe and its instrumentation chain. This calibration was performed with the field probe, attached to its instrumentation. The response of the probe system to a CW field at the frequency of interest is compared to its response to a modulated signal with equal peak amplitude to that of a CW signal. The field level of the test signals are ensured to be more than 10 dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated reading was applied to the DUT measurements.

All voice modes for this device have been investigated in this section of the report. According to the FCC 3G Measurement Procedures, May 2006 for RF Emissions, variations in peak field and power readings.

This was done using the following procedure:

- 1. The probe was illuminated with a CW signal at the intended measurement frequency and wireless device power.
- 2. The probe was positioned at the field maxima over the dipole antenna (determined after an area scan over the dipole) illuminated with the CW signal.
- 3. The reading of the probe measurement system of the CW signal at the maximum point was recorded.
- Using a Spectrum Analyzer, the modulated signal adjusted with the same peak level of the CW signal was determined.
- The probe measurement system reading was recorded with the modulated signal. The appropriate system crest factors for the modulation type were configured in the software to the system measurements.
- The ratio of the CW reading to modulated signal reading is the probe modulation factor (PMF) for the modulation and field probe combination. This was repeated for 80% AM.
- 7. Steps 1-6 were repeated at all frequency bands and for both E and H field probes.

The modulation factors obtained were applied to readings taken of the actual wireless device, in order to obtain an accurate peak field reading using the formula:

$$Peak = 20 \cdot log (Raw \cdot PMF)$$

This method correlates well with the modulation using the DUT in the alternative substitution method. See below for correlation of signal:

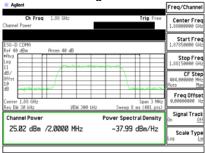


Figure 19 Signal Generator Modulated Signal

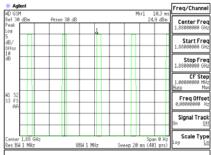


Figure 20 Wireless Device Modulated Signal

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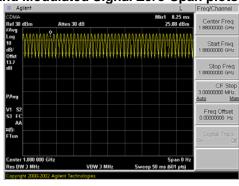
Modulation Factors:

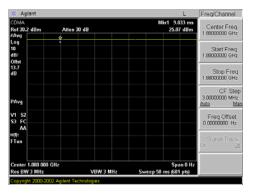
f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	E-Field Modulation Factor	H-Field Modulation Factor
835	AM	226.80	0.6312	1.388	1.258
835	CDMA	335.30	1.0040	0.939	0.791
835	CW	314.90	0.7941		
1880	AM	207.90	0.6922	1.373	1.086
1880	CDMA	294.80	1.1200	0.968	0.671
1880	CW	285.50	0.7515		
	f (MHz)	Protocol	E-Field (V/m)	E-Field Modulation Factor	
	1880	CDMA / SO3	46.76	2.114	
	1880	CW	98.85		1

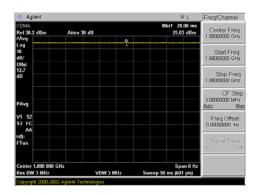
Figure 21
Modulation Factors

<u>FCC 3G Note:</u> CDMA represents RC3/SO2 mode, while CDMA/SO3 represents RC1/SO3 mode. Other modes were investigated and were within 0.25 dB of the RC3/SO2 configuration per Table 10-1.

CW and Modulated Signal Zero-Span plots:







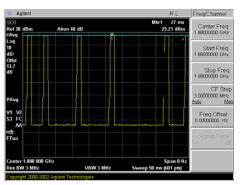


Figure 22 Zero-Span Plots

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9. FCC 3G MEASUREMENTS - MAY/JUNE 2006

Sample pre-testing of the various modes were performed at the worst case probe location as part of subset testing justification. See below for measured conducted power for applicable device modes:

I. **Handset Measured Conducted Powers:**

FCC 3G Maximum Measured Conducted Powers for SCH-U520

Band	Channel	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]
		RC1/1	RC3/3	RC1/1	RC3/3
Cellular	1013	25.48	25.26	25.37	25.32
	384	25.09	25.02	24.96	24.91
	777	25.54	25.34	25.53	25.41
	25	24.72	24.72	24.65	24.67
PCS	600	24.68	24.76	24.58	24.62
	1175	24.81	24.89	24.74	24.73

II. Worst-Case Probe Location Measurements

Below are RC/SO mode investigation results of the device at the worst-case (maximum) field point location. The worst-case RC/SO was used for T-coil testing.

Table 9-2 Handset 3G mode variation on RF Emissions

Mode	Channel	RC/SO	Antenna	Time Avg. Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT
E-field Emissions								
PCS	600	SO55/RC3	Fixed	31.2	29.6	41.0	-11.39	M4
PCS	600	SO3/RC1	Fixed	14.8	29.9	41.0	-11.10	M4
PCS	600	SO55/RC1	Fixed	31.2	29.6	41.0	-11.40	M4
PCS	600	SO2/RC1	Fixed	30.4	29.4	41.0	-11.64	M4
PCS	600	SO2/RC3	Fixed	31.1	29.6	41.0	-11.42	M4

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10. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSCHU520
Model:	SCH-U520
S/N:	1C140426

I. E-FIELD EMISSIONS:

Table 10-1
HAC Data Summary for E-field

	TIAO Data Gammary for E-ficia													
Mode	Channel	Backlight	RC/SO	Scan Center	Battery	Antenna	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.3.1.2.2	
E-field Emissions														
CDMA	1013	off	SO55/RC3	Acoustic	Standard	Fixed	25.00	77.4	37.2	51.0	-13.77	M4	none	
CDMA	384	off	SO55/RC3	Acoustic	Standard	Fixed	24.91	94.3	38.9	51.0	-12.05	M4	none	
CDMA	777	off	SO55/RC3	Acoustic	Standard	Fixed	25.41	78.4	37.3	51.0	-13.66	M4	none	
PCS	25	off	SO55/RC3	Acoustic	Standard	Fixed	24.67	28.2	28.7	41.0	-12.29	M4	none	
PCS	600	off	SO55/RC3	Acoustic	Standard	Fixed	24.62	30.9	29.5	41.0	-11.47	M4	none	
PCS	1175	off	SO55/RC3	Acoustic	Standard	Fixed	24.73	30.2	29.3	41.0	-11.67	M4	none	

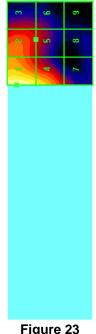


Figure 23
Sample E-field Scan Overlay
(See Test Setup Photographs for actual WD overlay)

Note: Worst-case measurement evaluated for worst-case 1/8 rate gating condition in RC1/SO3; Mute=Yes

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FCC ID:	A3LSCHU520
Model:	SCH-U520
S/N:	1C140426

II. H-FIELD EMISSIONS:

Table 10-2 HAC Data Summary for H-field

							<u> </u>						
Mode	Channel	Backlight	RC/SO	Scan Center	Battery	Antenna	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.3.1.2.2
H-field Em	issions												
CDMA	1013	off	SO55/RC3	Acoustic	Standard	Fixed	25.32	0.133	-19.6	0.6	-20.16	M4	none
CDMA	384	off	SO55/RC3	Acoustic	Standard	Fixed	24.91	0.152	-18.4	0.6	-19.00	M4	none
CDMA	777	off	SO55/RC3	Acoustic	Standard	Fixed	25.41	0.127	-20.0	0.6	-20.57	M4	none
PCS	25	off	SO55/RC3	Acoustic	Standard	Fixed	24.67	0.069	-26.7	-9.4	-17.35	M4	none
PCS	600	off	SO55/RC3	Acoustic	Standard	Fixed	24.62	0.092	-24.2	-9.4	-14.76	M4	none
PCS	1175	off	SO55/RC3	Acoustic	Standard	Fixed	24.73	0.075	-26.0	-9.4	-16.57	M4	none

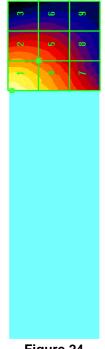


Figure 24
Sample H-field Scan Overlay
(See Test Setup Photographs for actual WD overlay)

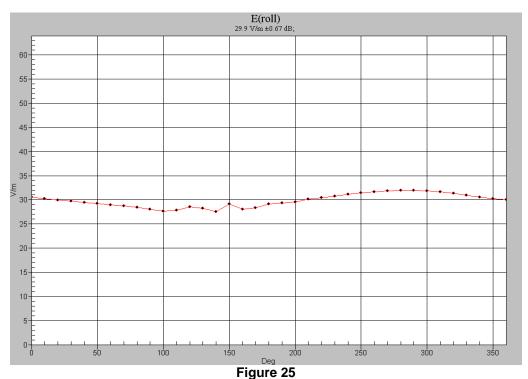
FCC ID: A3LSCHU520	PCTEST.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager		
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FCC ID:	A3LSCHU520
Model:	SCH-U520
S/N:	1C140426

III. Worst-case Configuration Evaluation

Table 10-3 Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Channel	Backlight	RC/SO	Scan Center	Battery	Antenna	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT
Probe Rotat	Probe Rotation at Worst-case											
PCS	600	off	SO55/RC3	Acoustic	Standard	Fixed	24.62	32.0	29.8	41.0	-11.19	M4



Worst-Case Probe Rotation about Azimuth axis

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^{*} Note: Location of probe rotation is shown in Figure 23 or Figure 24

11. EQUIPMENT LIST

Manufacturer	Model / Equipment	Calibration Date	Cal Inerval	Calibration Due	Serial No.
Agilent	E4404B/E4407B ESA Spectrum Analyzer	4/20/2006	Annual	4/20/2007	US39210313
Agilent	N4010A Wireless Connectivity Test Set	6/11/2006	Annual	6/11/2007	GB46170464
Agilent	E5515C Wireless Communications Test Set	7/27/2006	Annual	7/27/2007	GB41450275
Agilent	E5515C Wireless Communications Test Set	10/6/2006	Annual	10/6/2007	GB43193972
Agilent	E4432B ESG-D Series Signal Generator	8/8/2006	Annual	8/8/2007	US40053896
Agilent	8648D (9kHz-4GHz) Signal Generator	10/1/2006	Annual	10/1/2007	3613A00315
Rohde & Schwarz	CMU200 Base Station Simulator	1/31/2006	Annual	1/31/2007	109892
Rohde & Schwarz	CMU200 Base Station Simulator	7/26/2006	Annual	7/26/2007	833855/010
Rohde & Schwarz	CMU200 Base Station Simulator	7/26/2006	Annual	7/26/2007	650378
SPEAG	CD835V3 Freespace 835 MHz Dipole	2/23/2005	Biennial	2/23/2007	1003
SPEAG	CD1880V3 Freespace 1880 MHz Dipole	2/23/2005	Biennial	2/23/2007	1002
SPEAG	CD2450V3 Freespace 2450 MHz Dipole	2/24/2005	Biennial	2/24/2007	1004
SPEAG	H3DV6 Freespace H-field Probe	1/20/2006	Annual	1/20/2007	6180
SPEAG	ER3DV6 Freespace E-field Probe	3/22/2006	Annual	3/22/2007	2332
SPEAG	DAE4	6/1/2006	Annual	6/1/2007	704
SPEAG	CD835V3 Freespace 835 MHz Dipole	7/1/2006	Biennial	6/30/2008	1082
SPEAG	CD1880V3 Freespace 1880 MHz Dipole	7/1/2006	Biennial	6/30/2008	1064
SPEAG	CD2450V3 Freespace 2450 MHz Dipole	7/1/2006	Biennial	6/30/2008	1062
SPEAG	H3DV6 Freespace H-field Probe	7/10/2006	Annual	7/10/2007	6207
SPEAG	ER3DV6 Freespace E-field Probe	7/10/2006	Annual	7/10/2007	2335
SPEAG	DAE4	9/4/2006	Annual	9/4/2007	665

Table 11-1 Equipment List

 * Calibration traceable to the National Institute of Standards and Technology (NIST).

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12. MEASUREMENT UNCERTAINTY

Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Unc. (dB)	Notes/Comments
Measurement System						
RF System Reflections	0.50	Tolerance	R	1.73	0.30	* Refl. < -20 dB
RF Ambient Conditions	0.20	Tolerance	R	1.73	0.12	
Field Probe Calibration	0.21	Tolerance	N	1.00	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	0.01	
Boundary Effects	0.105	Accuracy	R	1.73	0.06	*
Sensor Displacement	0.66	Accuracy	R	1.73	0.40	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	0.03	*
System Detection Limit	0.05	Tolerance	R	1.73	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	0.02	*
Integration Time	0.11	Tolerance	R	1.73	0.06	*
Response Time	0.033	Tolerance	R	1.73	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	0.06	*
Test Sample Related						
Device Positioning Vertical	0.2	Tolerance	R	1.73	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	0.06	*
Power Drift	0.21	Tolerance	R	1.73	0.12	
Combined Standard Uncertainty (k=1)						14.7%
Expanded Uncertainty [95% confidence]						29.4%

Table 12-1Uncertainty Estimation Table

Notes

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
 equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
 and NIST Tech Note 1297 and UKAS M3003.
- 2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

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13. TEST DATA

See following Attached Pages for Test Data.

FCC ID: A3LSCHU520	PCTEST.	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
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DUT: HAC Dipole 835 MHz

Type: CD835V3 Serial: 1003

Communication System: CW; Frequency: 835 MHz;

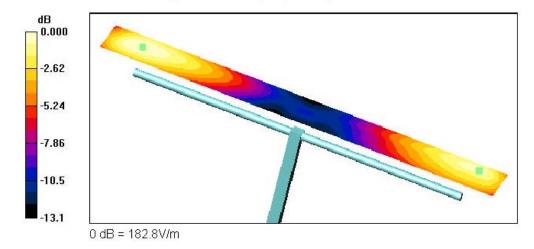
Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 7/10/2006
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn704; Calibrated: 6/1/2006
- · Phantom: HAC Test Arch with Coil; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 44;

835MHz, 100mW/20dBm/Hearing Aid Compatibility Test (41x361x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Reference Value = 112.2 V/m; Power Drift = 0.009 dB Average value of Total (interpolated) = 178.85 V/m



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DUT: HAC Dipole 1900 MHz

Type: CD1880V3 Serial: 1002

Communication System: CW; Frequency: 1880 MHz;

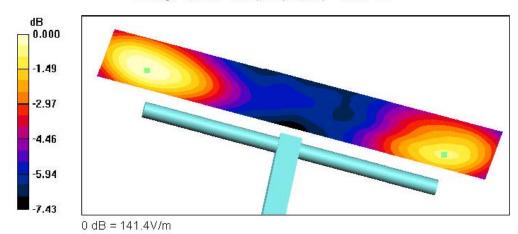
Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 7/10/2006
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn704; Calibrated: 6/1/2006
- Phantom: HAC Test Arch with Coil; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 44;

1880MHz, 100mW/20dBm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Reference Value = 145.9 V/m; Power Drift = 0.019 dB Average value of Total (interpolated) = 135.0 V/m



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DUT: HAC Dipole 835 MHz

Type: CD835V3 Serial: 1003

Communication System: CW; Frequency: 835 MHz;

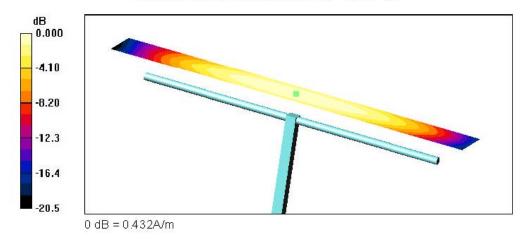
Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6207: Calibrated: 7/10/2006
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn704; Calibrated: 6/1/2006
- Phantom: HAC Test Arch with Coil; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 44;

835MHz, 100mW/20dBm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Reference Value = 0.460 A/m; Power Drift = -0.018 dB Maximum value of Total (interpolated) = 0.432 A/m



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DUT: HAC Dipole 1900 MHz

Type: CD1880V3 Serial: 1002

Communication System: CW; Frequency: 1880 MHz;

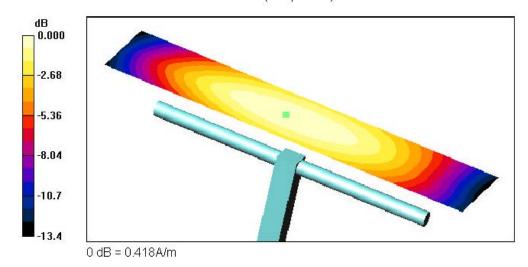
Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 7/10/2006
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn704; Calibrated: 6/1/2006
- Phantom: HAC Test Arch with Coil; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 44;

1880MHz, 100mW/20dBm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Reference Value = 0.413 A/m; Power Drift = 0.040 dB Maximum value of Total (interpolated) = 0.418 A/m



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DUT: SCH-U520

Type: Dual-Band CDMA Phone Serial: 1C140426 Backlight off Duty Cycle: 1:1

Communication System: Cellular CDMA; Frequency: 836.52 MHz;

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 7/10/2006
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn704; Calibrated: 6/1/2006
- Phantom: HAC Test Arch with Coil; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 44;

Mid.ch/Hearing Aid Compatibility Test (251x251x1): Measurement grid: dx=2mm, dy=2mm

Maximum value of peak Total field = 88.6 V/m Probe Modulation Factor = 0.939 Reference Value = 88.9 V/m; Power Drift = -0.242 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 75.1	Grid 2 84.8	Grid 3 79.4
Grid 4 78.0	Grid 5 88.6	Grid 6 84.6



Note: Under ANSI C63.19-2006 limits, this configuration has a Hearing Aid Near-Field Category of M4.

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DUT: SCH-U520

Type: Dual-Band CDMA Phone Serial: 1C140426 Backlight off Duty Cycle: 1:1

Communication System: PCS CDMA; Frequency: 1880 MHz;

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 7/10/2006
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn704; Calibrated: 6/1/2006
- Phantom: HAC Test Arch with Coil; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 44;

Mid.ch/Hearing Aid Compatibility Test (251x251x1): Measurement grid: dx=2mm, dy=2mm

Maximum value of peak Total field = 29.9 V/m Probe Modulation Factor = 0.968 Reference Value = 18.4 V/m; Power Drift = 0.949 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 29.9	Grid 2 24.2	Grid 3 20.5
Grid 4 27.8	Grid 5 20.6	Grid 6 19.7
Grid 7 20.4	Grid 8 16.5	Grid 9 15.4



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DUT: SCH-U520

Type: Dual-Band CDMA Phone Serial: 1C140426 Backlight off Duty Cycle: 1:1

Communication System: Cellular CDMA; Frequency: 836.52 MHz;

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 7/10/2006
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn704; Calibrated: 6/1/2006
- Phantom: HAC Test Arch with Coil; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 44;

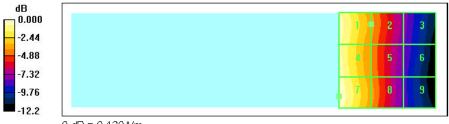
Mid.ch/Hearing Aid Compatibility Test (251x251x1): Measurement grid: dx=2mm, dy=2mm

Maximum value of peak Total field = 0.120 A/m Probe Modulation Factor = 0.791 Reference Value = 0.079 A/m; Power Drift = -0.352 dB Hearing Aid Near-Field Category: W4 (AWF 0 dB)

	Grid 2 0.079	
Grid 4	Grid 5	Grid 6
0.115	0.077	0.048

Peak H-field in A/m

Grid 7 Grid 8 Grid 9 0.120 0.079 0.046



() d	В=	0.1	20A/	m

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DUT: SCH-U520

Type: Dual-Band CDMA Phone Serial: 1C140426 Backlight off Duty Cycle: 1:1

Communication System: PCS CDMA; Frequency: 1880 MHz;

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6207; Calibrated: 7/10/2006
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn704; Calibrated: 6/1/2006
- Phantom: HAC Test Arch with Coil; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 44;

Mid.ch/Hearing Aid Compatibility Test (251x251x1): Measurement grid: dx=2mm, dy=2mm

Maximum value of peak Total field = 0.062 A/m Probe Modulation Factor = 0.671 Reference Value = 0.055 A/m; Power Drift = -0.167 dB Hearing Aid Near-Field Category: W4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.062	0.046	0.032
Grid 4	Grid 5	Grid 6
0.053	0.044	0.032
Grid 7	Grid 8 0.035	Grid 9



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